

Field Effect Transistors (Schockley, 1952)

Voltage variable resistors

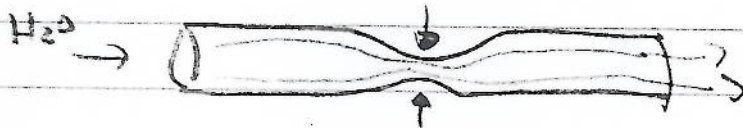
First half of story:

Consider water hose



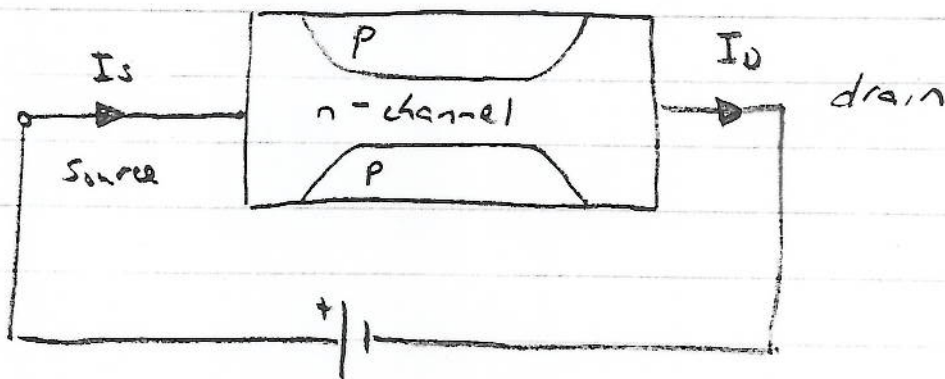
Some impedance to flow

Now pinch it



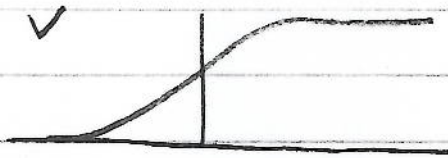
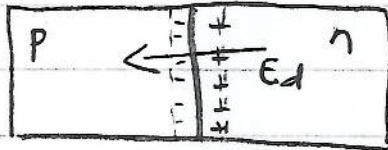
increased impedance

Consider



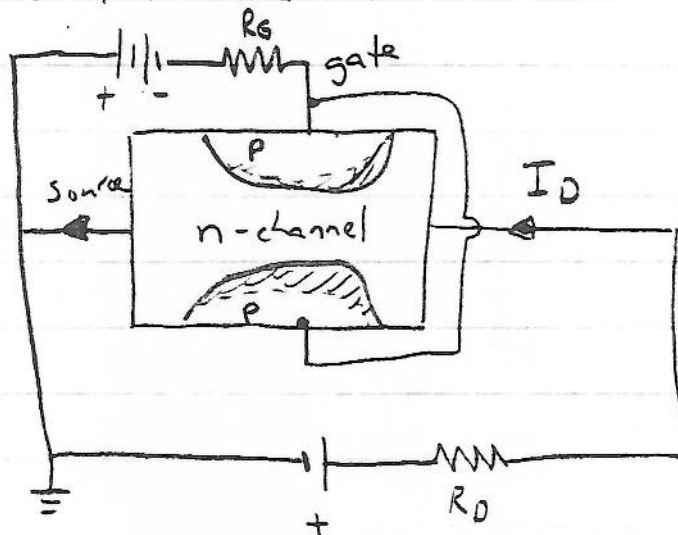
n doped material makes channel.
why?

Recall, again n-p junction

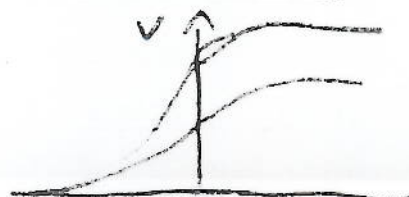
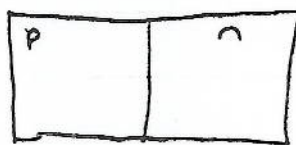


Electric field sweeps away carriers $\rightarrow$ depletion region
 $\rightarrow$ insulating

Now, pinch the hose



Reverse biasing P-n junctions



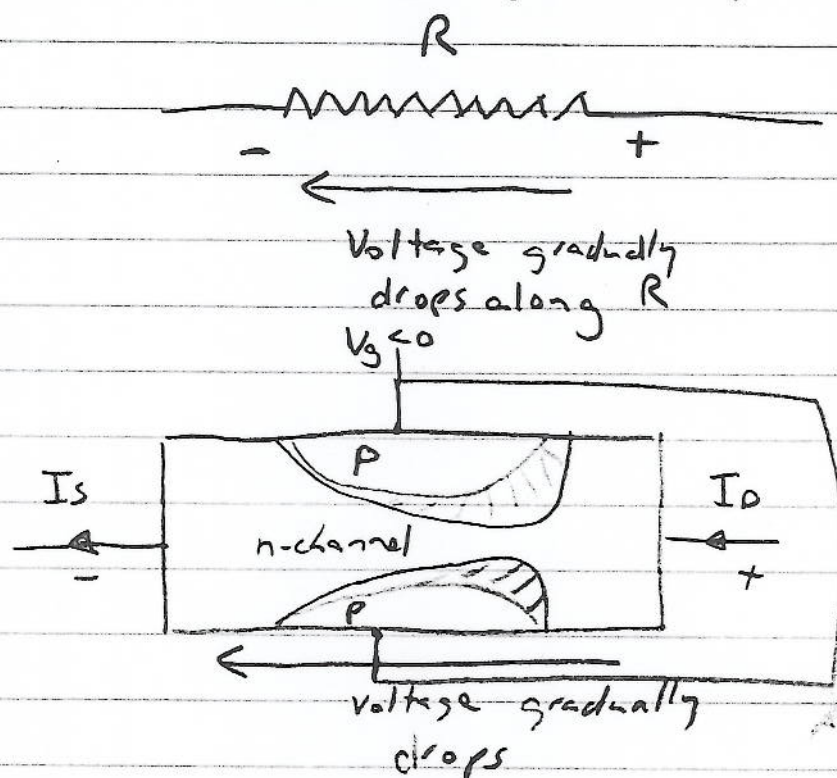
depletion region increases
 at expense of n-channel

(4) →

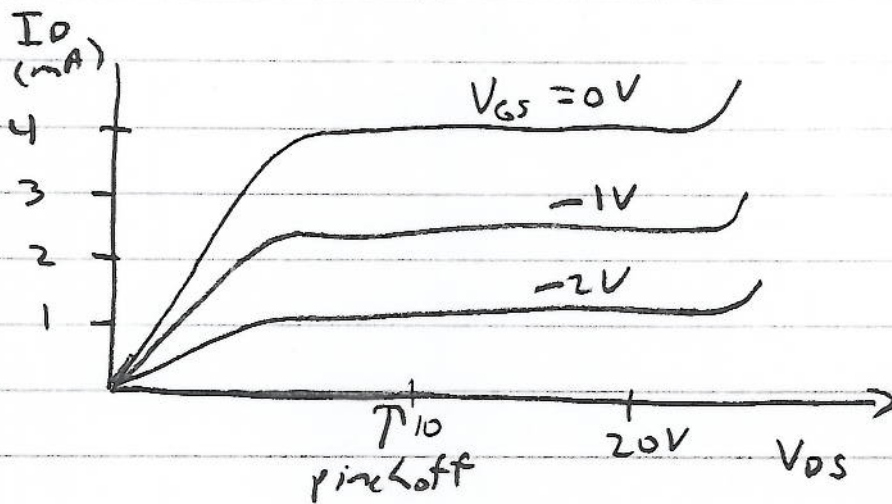
$$r = \rho \frac{l}{A} \quad \text{smaller } A, \text{ bigger } r$$

Second half of story

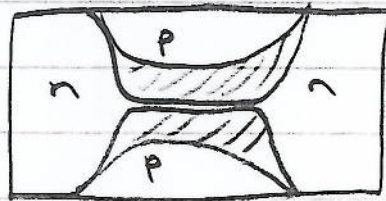
n channel like a (voltage variable) resistor



This effect gives $R_{SD} = f(V_{DS})$ - non 0 Ω at $V_{DS} = 0$

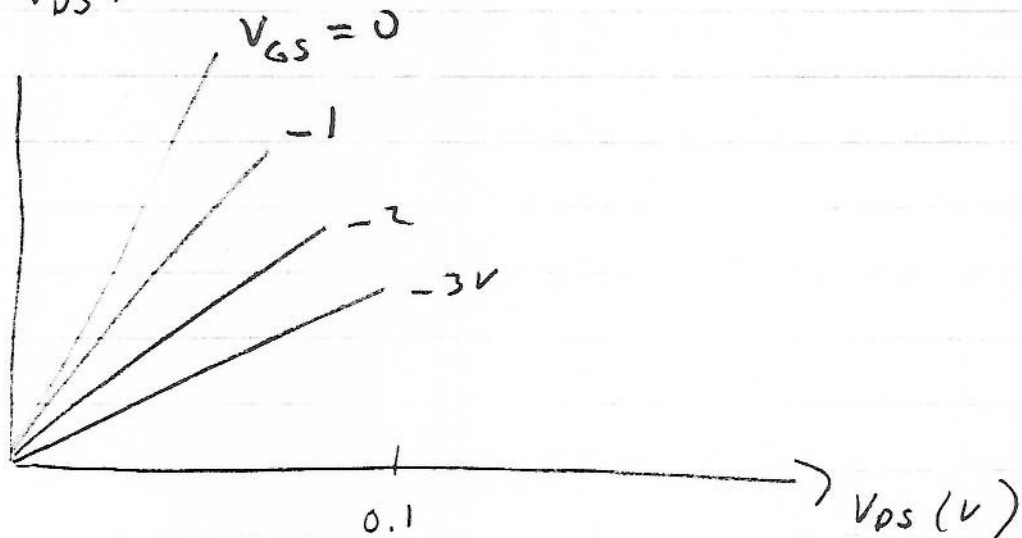


For V_{GS} large enough



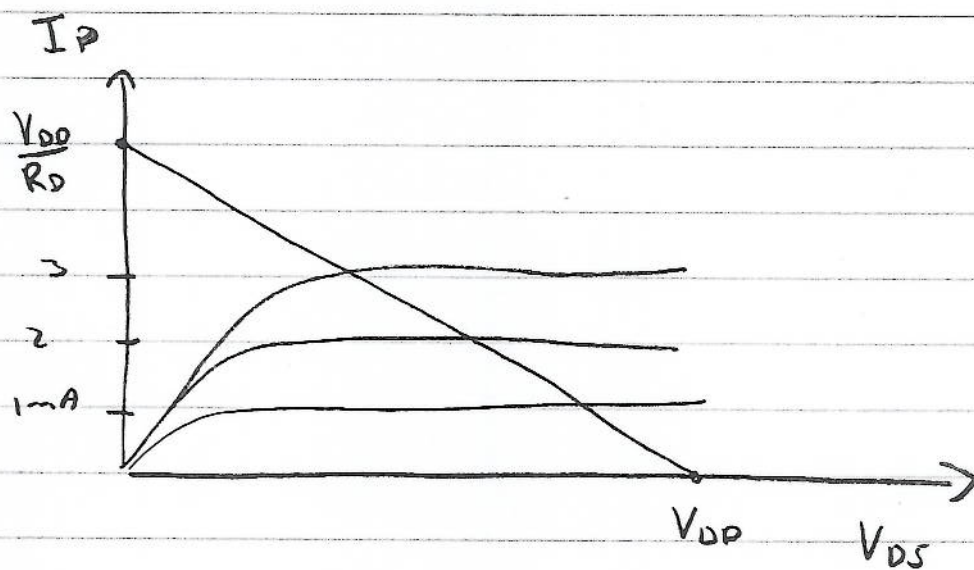
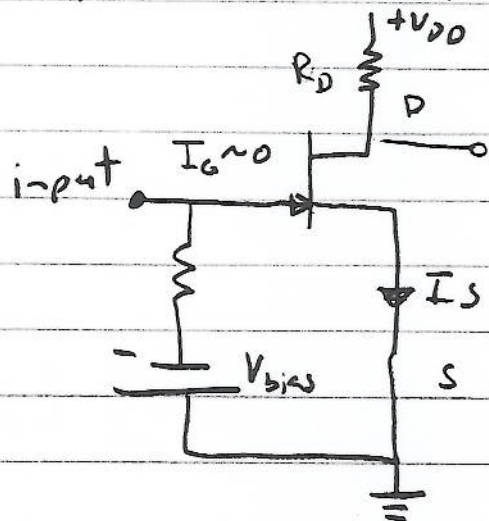
pinchoff $\rightarrow$ no conduction from drain to source
 $\rightarrow$ pinchoff

Low V_{DS} :



Linear, variable resistance
 VCR - voltage controlled resistance

Common source FET Amplifier - like common emitter



$$V_{DD} - I_D R_D - V_{DS} = 0$$

$$I_D = \frac{V_{DD}}{R_D} - \frac{V_{DS}}{R_D}$$

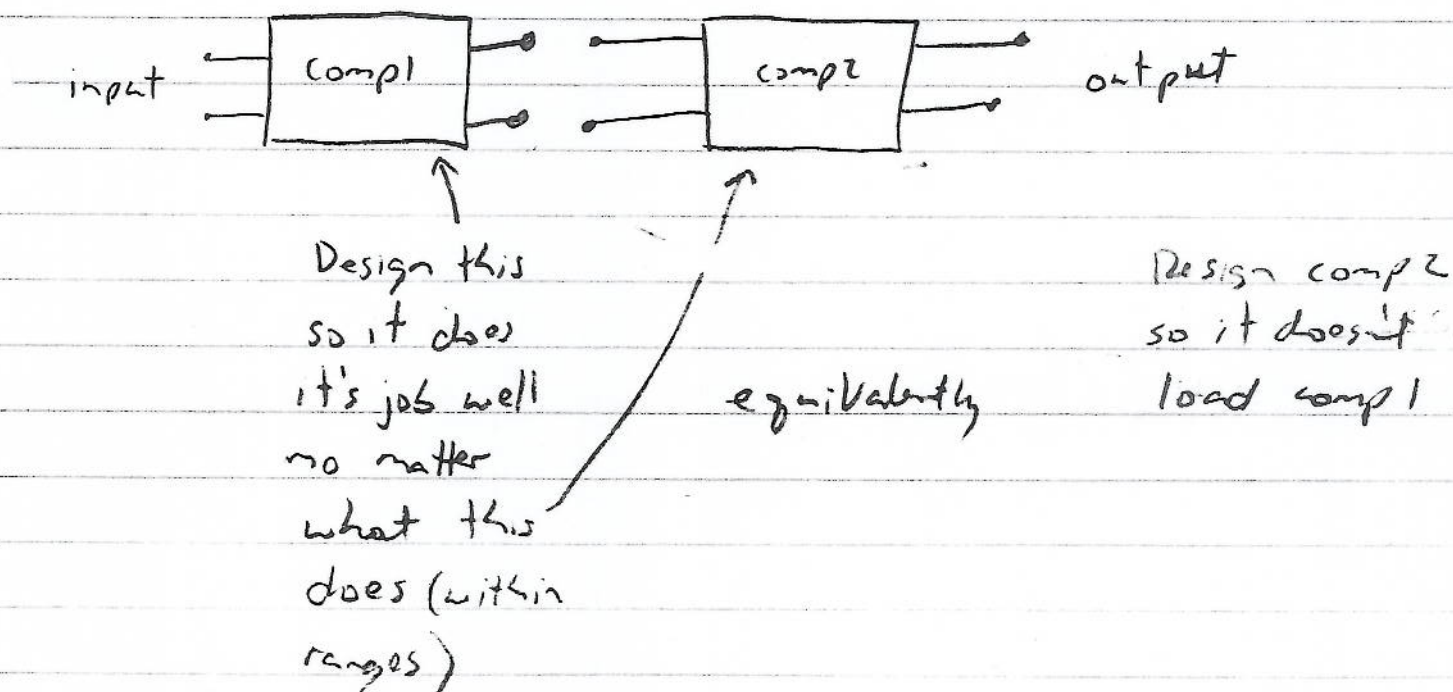
Nice thing about FET amps:
gate-source is reverse biased
→ high R between them

So what?

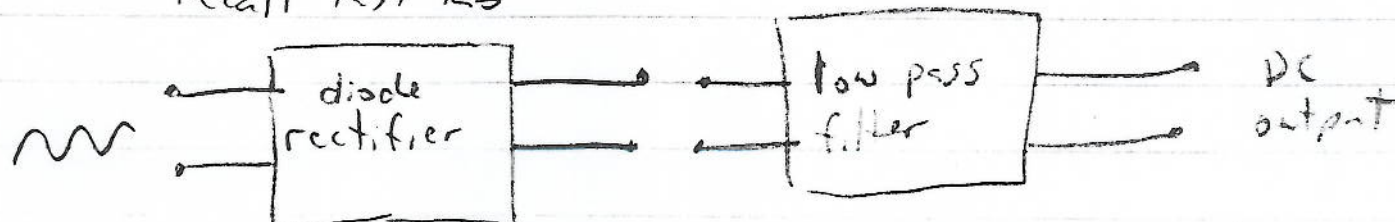
In general, want components to have

- 1) Large input Z
- 2) small output Z

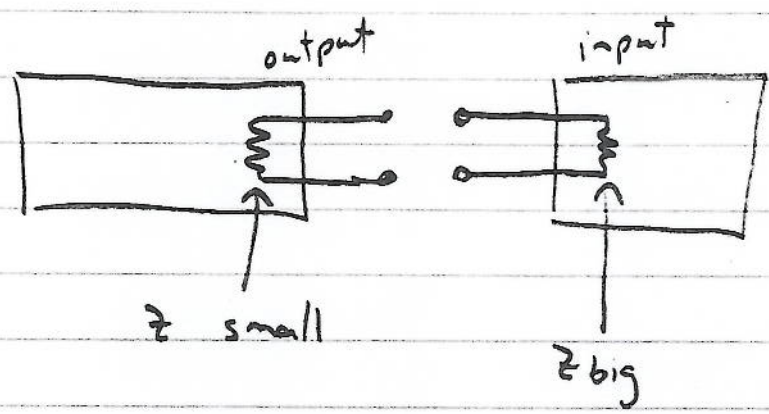
Often string together components



Recall last lab

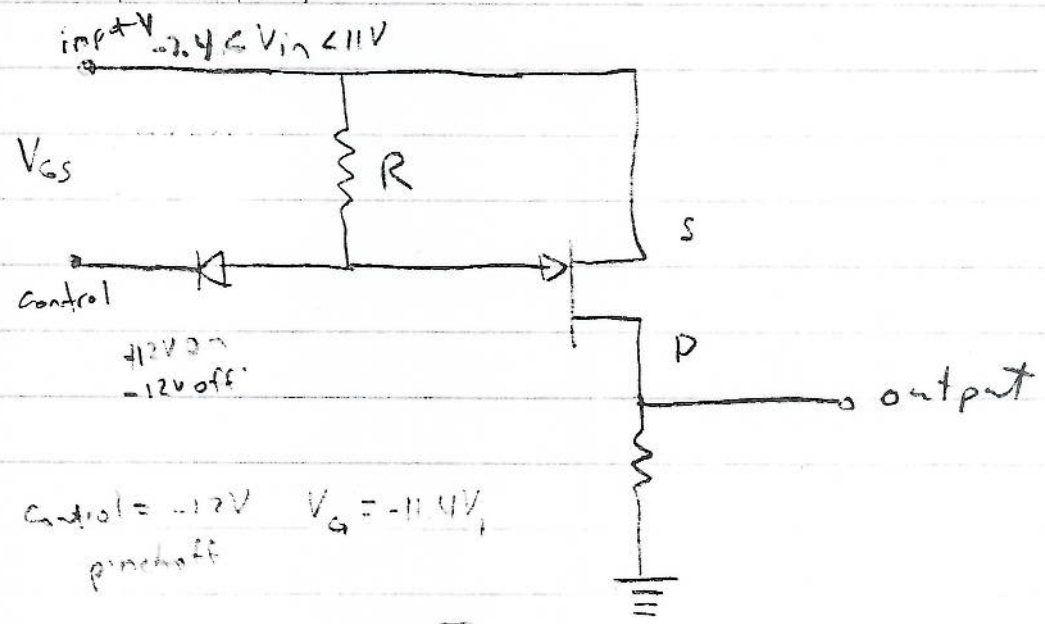


Want

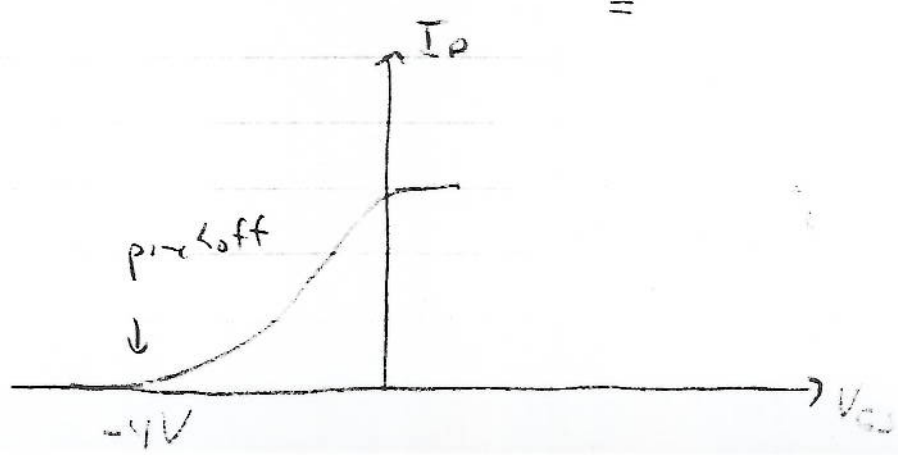


FETs have large Z_{input} .

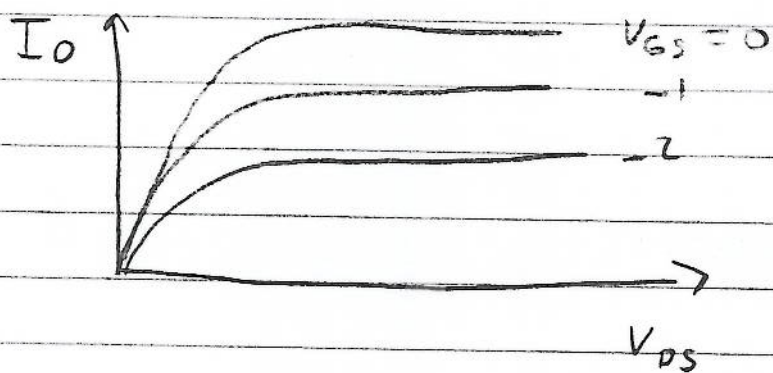
FET switch



Control = -12V $V_G = -11.4V$,
pinch off



FET constant current source

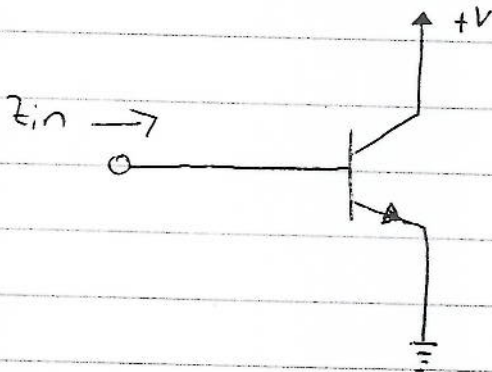


Input Impedance to a transistor (BJT) base

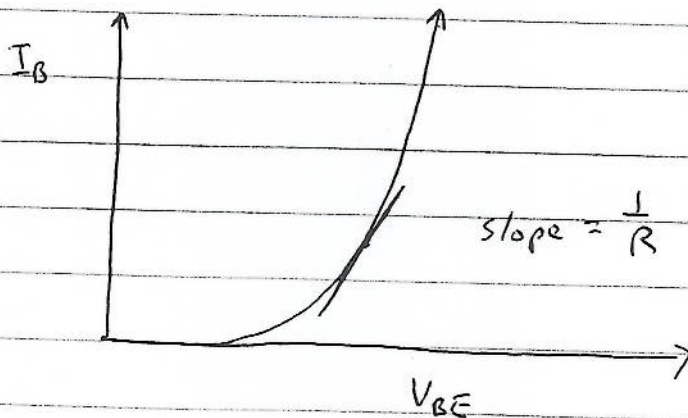
Interested in A.C. impedance

$$Z_{AC} = \partial V / \partial I$$

First, look at grounded emitter



Recall Base-emitter characteristic

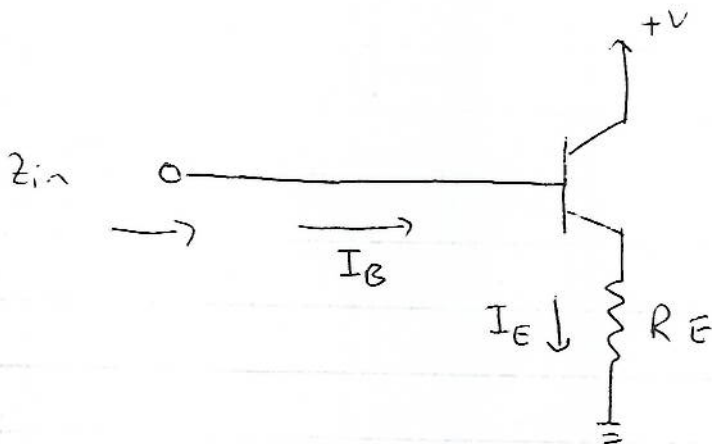


Impedance, h_{ie} , depends where transistor is biased

$$\sim 1k\Omega$$

less at higher bias currents

Now consider



If we put I_B into base

$I_E = \beta I_B$ flows into emitter load through emitter resistance

V_E goes up by $I_E R_E = \beta I_B R_E$

Since $V_{BE} = \text{const}$ V_B goes up w/ V_E

$$z_{\text{into base from } R_E} = \frac{\partial V_B}{\partial I_B} = \frac{\beta I_B R_E}{I_B} = \beta R_E$$

Total $z_{\text{into base}}$

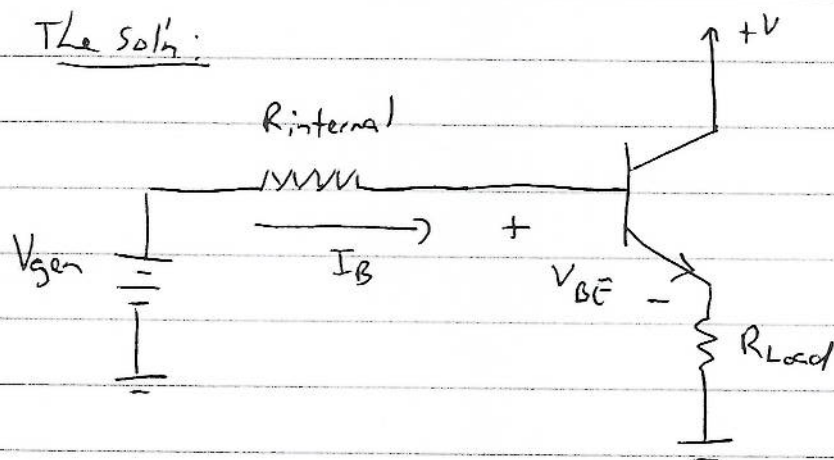
$$z_{\text{into base}} = h_{ie} + \beta R_E$$

This is basis for "emitter follower"
or "buffer circuit"

The problem

Suppose we have voltage generator w/ high internal impedance which we want to use to drive a low impedance load.

The sol'n:



Z_{in} made large even though R_{Load} may be small, by β of transistor

Disadvantages

- (1) nearly constant offset V_{BE} .
No biggie if $V_{gen} > V_{BE}$
- (2) Only works for $V_{gen} +$.

* Feedback

Take some fraction of output $\rightarrow$ send it back to input

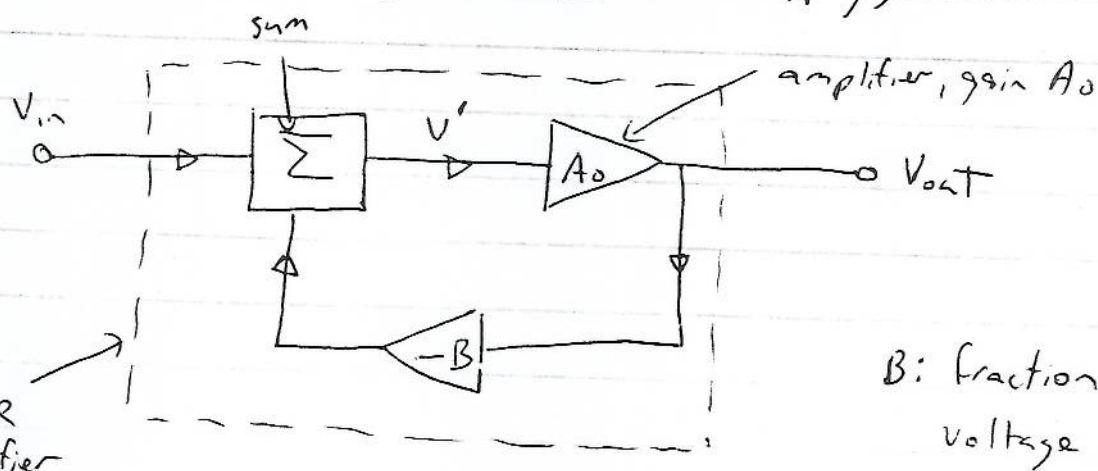
In phase, positive feedback

- increase gain
- generate constant or repetitive output

Out of phase, negative feedback

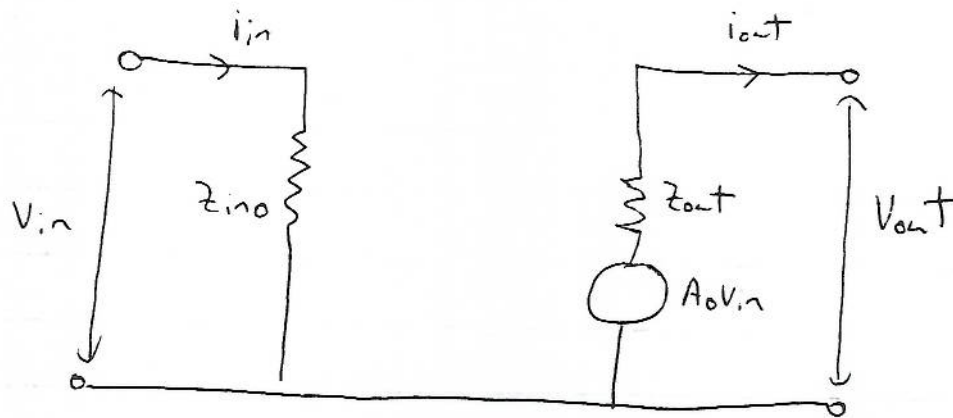
- increase circuit stability
 - temperature
 - power supply voltage fluctuations
 - radiation damage, aging of transistors
- increased input impedance
- decreased output impedance
- decreased distortion
- increased bandwidth

Negative Voltage Feedback (bootstrapping)

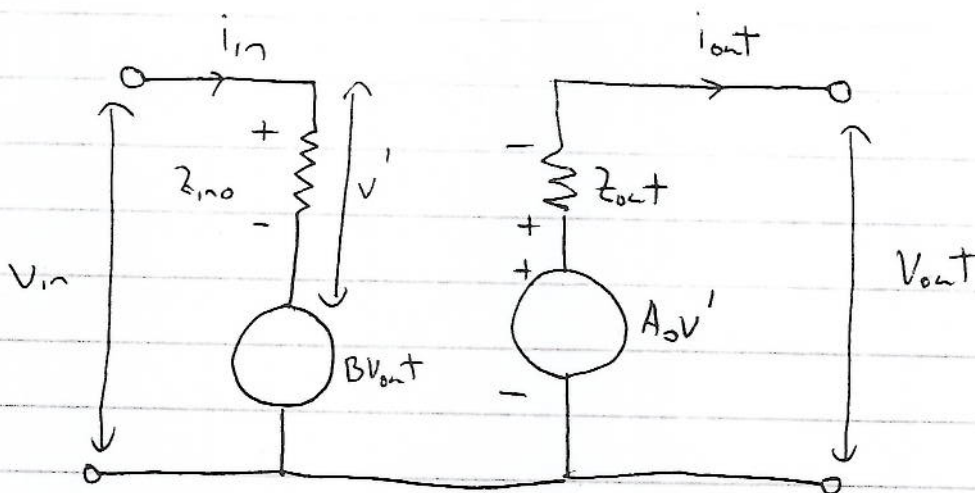


$$V' = V_{in} - B V_{out}$$

B : fraction of output voltage subtracted from input; feedback factor



no feedback



$$V' = V_{in} - B V_{out}$$

With feedback

$$V_{in} = V' + B V_{out}$$

$$V' = i_{in} z_{in0}$$

$$\left(A_f = \frac{V_{out}}{V_{in}} = \frac{A_0}{1 + A_0 B} \right)$$

$$A_o = \frac{V_{out}}{V'} \quad \text{open loop gain}$$

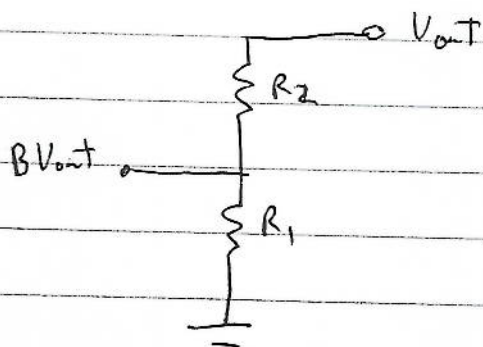
$$A_f = \frac{V_{out}}{V_{in}}$$

$$A_f = \frac{A_o V'}{V' + B V_{out}} = \frac{A_o V'}{V' + B A_o V'} = \frac{A_o}{1 + B A_o} \quad \text{smaller than } A_o$$

Nice thing #1:

If $A_o B$ large $A_f = \frac{1}{B}$ depends only on B , not A_o

B easy to make constant



$$B = \frac{R_1}{R_1 + R_2}$$

$$A_f = \frac{R_1 + R_2}{R_1} = 1 + \frac{R_2}{R_1}$$

Nice thing #2:

Increase input impedance

→ net effective input voltage reduced, smaller current

$$z_{inf} = \frac{V_{in}}{i_{in}} = \frac{V' + B V_{out}}{i_{in}} = \frac{i_{in} z_{ino} + B V_{out}}{i_{in}}$$

$$V_{in} = i_{in} z_{ino} + B V_{out}$$

$$V_{out} = V_{in} \frac{A_o}{1 + A_o B}$$

$$V_{in} = i_{in} z_{ino} + B V_{in} \frac{A_o}{1 + A_o B}$$

$$z_{inf} = \frac{V_{in}}{i_{in}} \quad V_{in} \left(1 - \frac{A_o B}{1 + A_o B} \right) = i_{in} z_{ino}$$

$$z_{inf} = \frac{z_{ino}}{1 - \frac{A_o B}{1 + A_o B}} = \underbrace{z_{ino} (1 + A_o B)}_{> 1 \text{ (nice thing \#2)}}$$

Nice thing #3:

Decrease output impedance

$$\text{Again, } V' = V_{in} - B V_{out}$$

$$V_{out} = A_o V' - i_{out} z_{out}$$

$$z_{out} = - \frac{\partial V_{out}}{\partial i_{out}}$$

Eliminate V'

$$V_{out} = A_o(V_{in} - \beta V_{out}) - i_{out} Z_{out}$$

$$V_{out} = \frac{A_o V_{in} - i_{out} Z_{out}}{1 + A_o \beta}$$

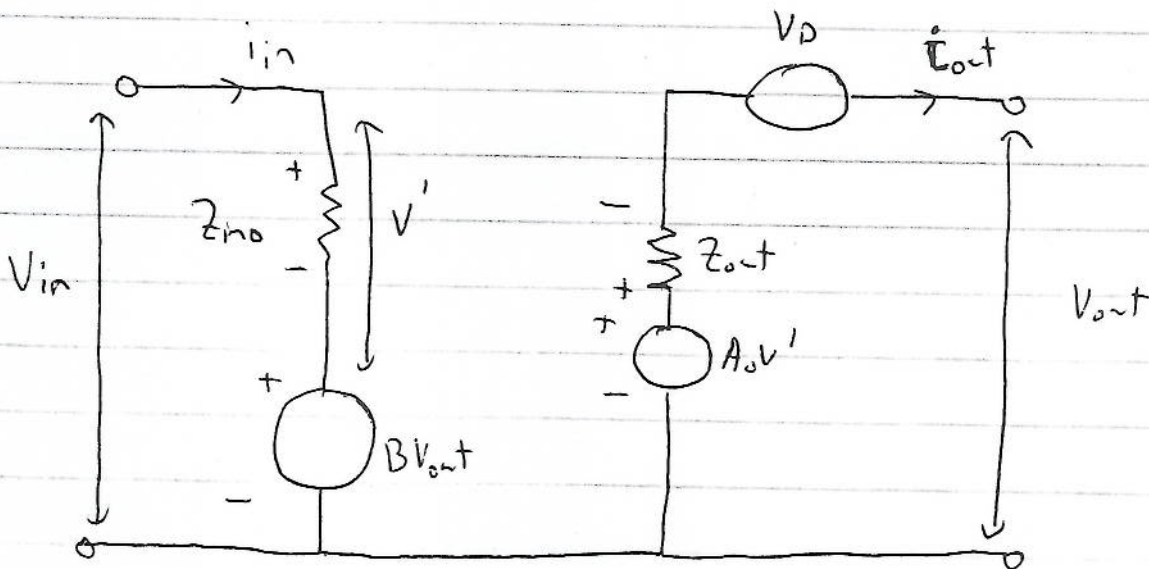
$$Z_{out_f} = \frac{Z_{out}}{1 + A_o \beta}$$

$$Z_{out_f} < Z_{out} \quad (\text{Nice thing \#3})$$

$\uparrow$ $\uparrow$
 w/ feedback w/o feedback

Nice thing \#4

Decrease of distortion



$$V_{out} = A_o v' - i_{out} z_{out} + V_D$$

$$V_{in} = v' + B V_{out}$$

Eliminate v'

$$V_{out} = A_o (V_{in} - B V_{out}) - i_{out} z_{out} + V_D$$

If i_{out} is small

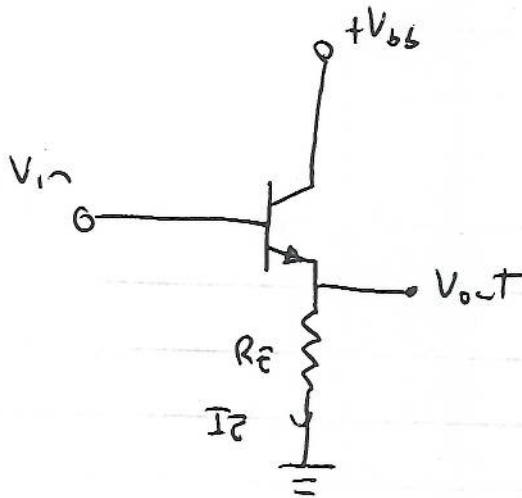
$$V_{out} = A_o (V_{in} - B V_{out}) + V_D$$

$$V_{out} (1 + A_o B) = A_o V_{in} + V_D$$

$$V_{out} = \frac{A_o}{1 + A_o B} V_{in} + \frac{1}{1 + A_o B} V_D \quad (\text{Nice thing \#4})$$

$\uparrow$
 Gain for bigger than Gain for
 V_{in} V_D

Emitter follower :



$$V_{in} = V_{BE} + I_E R_E$$

$$V_{out} = I_E R_E$$

$$V_{in} = V_{BE} + V_{out}$$

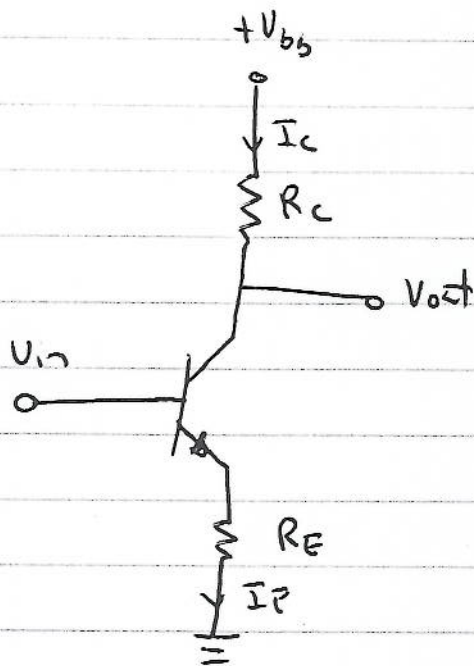
$$V_{BE} = V_{in} - V_{out}$$

Like negative voltage feedback

$$V' = V_{in} - B V_{out} \quad \text{w/ } B=1$$

$$A_f \approx \frac{1}{B} = 1$$

Common emitter



A.C. values

$$V_{in} = V_{BE} + I_E R_E \quad V_{out} = -I_C R_C$$

When $V_{in} \rightarrow +$ I_E increases $V_E \rightarrow +$ $V_{BE} < V_{in}$ $\rightarrow$ Negative feedback

$$I_C = \beta I_B$$

$$I_C + I_B = I_E$$

$$I_c + \frac{1}{\beta} I_c = I_E$$

$$I_c \left(1 + \frac{1}{\beta}\right) = I_E$$

$$I_c = \frac{\beta I_E}{\beta + 1}$$

So,

$$V_{in} = V_{BE} + R_E \frac{\beta + 1}{\beta} I_c$$

$$= V_{BE} - R_E \frac{\beta + 1}{\beta R_E} V_{out}$$

$$V_{BE} = V_{in} + \frac{\beta + 1}{\beta} \frac{R_E}{R_c} V_{out}$$

$$V' \rightarrow V_{BE}$$

$$V' = V_{in} - B V_{out}$$

$$B = - \frac{\beta + 1}{\beta} \frac{R_E}{R_c}$$

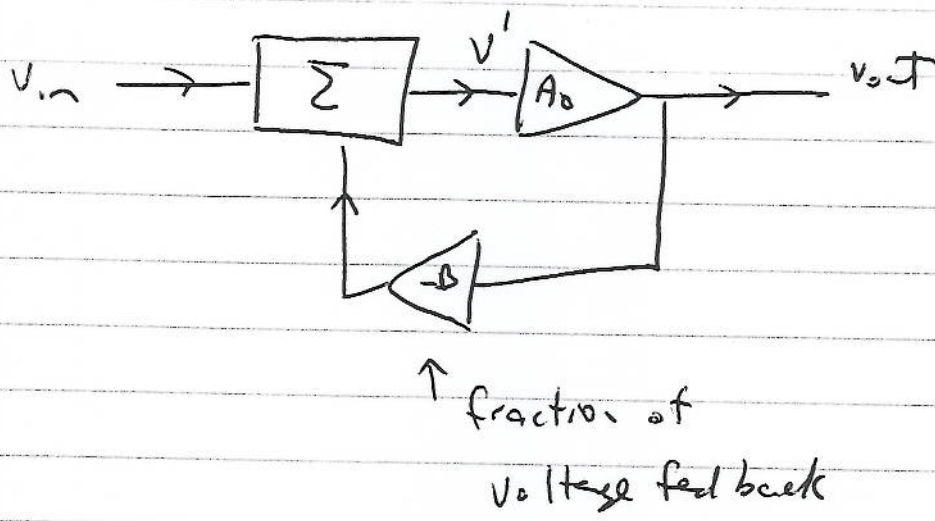
$$A_f \cong \frac{1}{B} = \frac{-\beta R_c}{(\beta + 1) R_E} \approx - \frac{R_c}{R_E}$$



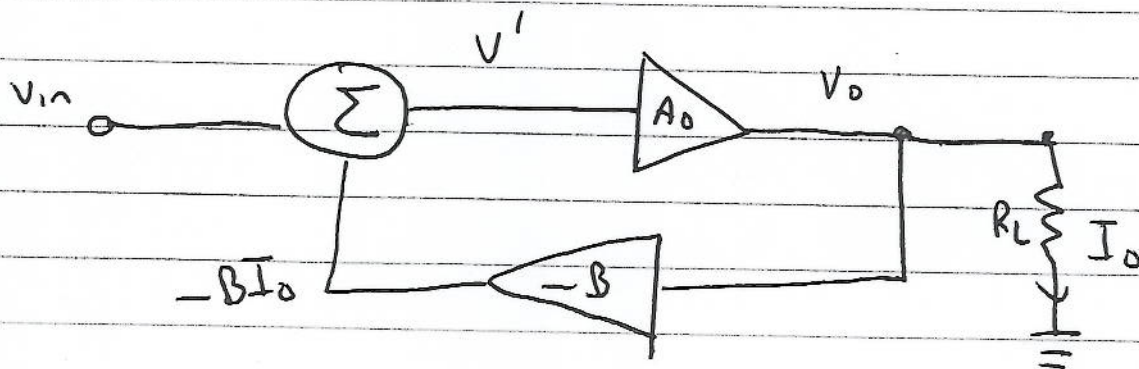
180° phase inversion

Negative current feedback
 $\rightarrow$ Constant current source

Remember



Now consider



$$V' = V_{in} - BI_o$$

$$BI_o = \frac{V_o}{R_L} B$$

$\uparrow$ voltage fed back $= BI_o$

$$V_o = I_o R_L = A_0 V'$$

3

$$I_o R_L = A_o (V_{in} - \beta I_o)$$

$$I_o (R_L + A_o \beta) = A_o V_{in}$$

$$I_o = \frac{A_o V_{in}}{R_L + A_o \beta}$$

If $A_o \beta \gg R_L$

$$I_o \approx \frac{V_{in}}{\beta} \quad \frac{I_o}{V_{in}} = \frac{1}{\beta}$$

Current output $\propto V_{in}$

$\frac{1}{\beta} \rightarrow$ transconductance